

INCHANGE SEMICONDUCTOR

Isc N-Channel MOSFET Transistor

STD18N65M5

D(2)

S(3)

3.0

• 100% : • Minimu	ent switching performance avalanche tested um Lot-to-Lot variations for robust de nance and reliable operation	PIN 1.Gate 2.Drain 3.Source		
	CATIONS ing applications			TO-252 package
• ABSO	LUTE MAXIMUM RATINGS(Ta=25	°C)		
• ABSO	LUTE MAXIMUM RATINGS(Ta=25° PARAMETER	°C) VALUE	UNIT	
			UNIT V	
SYMBOL	PARAMETER	VALUE		
SYMBOL V _{DSS}	PARAMETER Drain-Source Voltage	VALUE 650	V	
SYMBOL V _{DSS} V _{GSS}	PARAMETER Drain-Source Voltage Gate-Source Voltage Drain Current-Continuous@Tc=25°C	VALUE 650 ±25 15	V	
SYMBOL V _{DSS} V _{GSS}	PARAMETER Drain-Source Voltage Gate-Source Voltage Drain Current-Continuous@Tc=25°C (TJ=175°C) Tc=125°C	VALUE 650 ±25 15 9.4	V V A	
SYMBOL V _{DSS} V _{GSS} I _D I _{DM}	PARAMETER Drain-Source Voltage Gate-Source Voltage Drain Current-Continuous@Tc=25°C (TJ=175°C) Tc=125°C Drain Current-Single Pulsed	VALUE 650 ±25 15 9.4 60	V V A A	

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SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	th(ch-c) Channel-to-case thermal resistance		°C /W	
Rth(ch-a)	Channel-to-ambient thermal resistance		°C/W	

isc website: www.iscsemi.cn

F G Н

J Κ

1

0

0.65

2.10 2.10

0.40

0.90

9.90

2.50

2.40

1.10

10.

0. 60



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ELECTRICAL CHARACTERISTICS

$T_{C}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 1mA	650			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} = ±25V; I _D =0.25mA	3		5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =7.5A		198	220	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±25V;V _{DS} = 0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 650V; V _{GS} = 0V; T _J =25℃ T _J =125℃			1 100	μA
V _{SDF}	Diode forward voltage	I _{SD} =15A, V _{GS} = 0 V			1.5	v

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